## A Stochastic Local Hot Spot Alerting Technique

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- Motivation and Background
- Uncertainty-Aware Estimation Frameworks
- The Proposed Hot Spot Alerting Algorithm
- Experimental Results
- Conclusion

### Introduction

#### As IC process geometries shrink below 65nm

- Higher power density
- □ Higher operating temperature
- Lower circuit reliability
- Thermal control becomes a first-order concern
  - $\square$  Gate oxide lifetime is highly dependent on the T  $_{\rm J}$  of IC
  - □ Elevated temperature is a major contributor to lower IC reliability

#### Local hot spots becomes more prevalent in VLSI

- Non-uniform power density
- Degraded supply voltage levels
- Identifying and removing local hot spots is a major task

### **Prior Works**

K. Skadron, et al. (ISCA 2003)

□ Architectural-level thermal model, *HotSpot* 

W. Huang, et al. (DAC 2004)

Compact thermal model for temp-aware design

- D. Brook, et al. (HPCA 2001)
  Thermal control mechanism, Wattch
- J. Srinvasan, et al. (ICS 2003)
  Predictive dynamic thermal management
- R. Mukherjee, et al. (DAC 2006)
  Thermal sensor allocation and placement

### **Problem Statements**

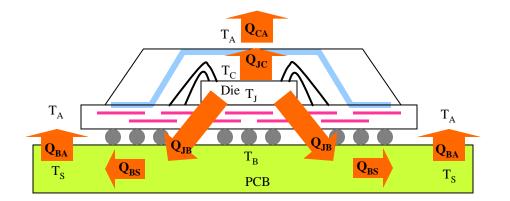
#### Much past work has examined techniques for:

- Thermal modeling
- Thermal management
- Thermal modeling, based on equivalent circuit models
  - Cannot consider real structures that have complex shapes and boundary conditions
- Thermal management, depends on thermal sensors
  - Can hardly observe peak power dissipation and resulting peak temp. (due to non-uniform power density)
- Gives rise to uncertainty in profiling local hot spots
  Renders the problem of identifying hot spots a stochastic one

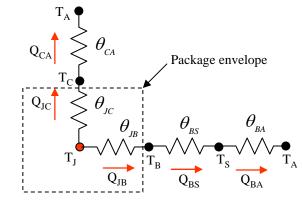
### Background (1/3)

#### IC package can be characterized by thermal resistance

- □ Heat is dissipated from the die into the ambient air
- Value of the thermal resistance determines the temperature rise of the junction above a reference point



Heat flow in the PBGA + HS package



One of the IC package heat transfer paths and the corresponding thermal resistive model

### Background (2/3)

Thermal resistance is defined as

$$\theta_{JX} = (T_J - T_X) / P$$

- $\Box$   $\theta_{JX}$  is the thermal resistance from device junction to specific point
- $\Box$  T<sub>J</sub> is the device junction temperature
- $\Box$  T<sub>x</sub> is the reference temperature for specific point
- $\square$  *P* is the device power dissipation
- When reference temperatures are specified for  $T_A$ ,  $T_B$ , or  $T_C$

$$\theta_{JA} = \frac{(T_J - T_A)}{P}$$
  $\theta_{JB} = \frac{(T_J - T_B)}{P}$   $\theta_{JC} = \frac{(T_J - T_C)}{P}$ 

Junction-to-air

Junction-to-board

Junction-to-case

 $\Box$   $T_A$ ,  $T_B$  and  $T_C$  are temperatures of ambient air, PCB board, and the case top

### Background (3/3)

Junction-to-air thermal resistance can be calculated as

$$\theta_{JA} = \left(\frac{1}{\theta_{JB} + \theta_{BS} + \theta_{BA}} + \frac{1}{\theta_{JC} + \theta_{CA}}\right)^{-1}$$

 $\Box$  The junction temperature can be estimated with:  $T_J = T_A + P \cdot \theta_{JA}$ 

□ The goal of thermal design is to maintain the  $\theta_{JA}$  value small so that the junction temperature  $T_J$  does not exceed some specified maximum value

•  $\theta_{JA}$  cannot be modeled directly due to the complexity of thermal models for package, cooling system, and board stack

 $\Box$   $\theta_{JA}$  is assumed to be a single parameter under the assumption that *P* is distributed uniformly across the die: *not realistic* 

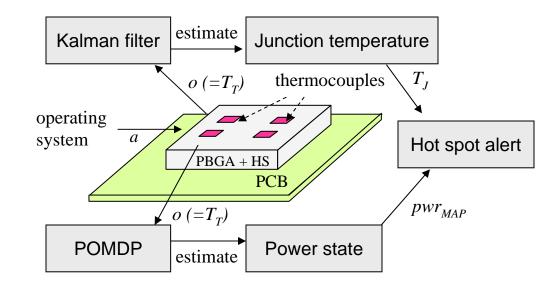
### **Motivation**

- Develop a hot spot alerting technique by estimating the junction temperature and the system power state
  - □ The thermal time constant of the die is larger than the circuit clock speed
  - Recognizing a temperature rise by relying on thermal sensors and subsequently employing thermal control mechanisms can result in too late a response
- Our proposed hot spot alerting technique combines:
  - □ State estimation for the junction temperature using Kalman Filter (KF)
  - State estimation for the system power dissipation using Partially Observable Markov Decision Process, (POMDP)



### **Overview of Estimation Framework**

• Use (external temperature) observations to estimate the Junction Temperature  $(T_J)$  and the Power state  $(pwr_{MAP})$ 



#### **Uncertainty-aware estimation framework**

### **Temperature Estimation Framework**

#### Kalman Filter

Estimate the state of a system based on the previous state, previous action, and the current observation

- Kalman Filter-based Temperature Estimation (KFTE)
  Framework
  - $\Box$  s is a state representing the junction temperature  $T_J$
  - □ *a* is a voltage-frequency assignment action given by an operating system
  - $\Box$  o is a temperature observation  $T_T$
  - **X** denotes a state transition matrix
  - □ Y denotes an action-input matrix
  - **Z** denotes an observation matrix

 $s^{t+1} = \mathbf{X}s^t + \mathbf{Y}a^t + u^t$ ,  $u^t \sim N(0, Q^t)$  *u*: temperature variation

 $o^{t+1} = \mathbf{Z}s^{t+1} + v^{t+1}, \quad v^{t+1} \sim N(0, R^{t})$  v: observation noise

### **Power Profile Estimation Framework (1/2)**

PODMP (Partially Observable Markov Decision Process)

To model the uncertainty in parameter observations

#### ■ POMDP is a tuple <*S*, *A*, *O*, *T*, *Z*> such that

- □ S is a finite set of states
- $\Box$  A is a finite set of actions
- O is a finite set of observations
- □ *T* is a state transition probability function
- Z is an observation function

#### POMDP maintains a belief state, b<sup>t</sup>(s)

□ A probability distribution over the possible states of the system

$$\Box \sum_{s \in S} b^t(s) = 1$$

### **Power Profile Estimation Framework (2/2)**

#### POMDP-based Power Profile Estimation (P3E) Framework

- □ *b* is a belief state about power state of the system
- □ *a* is an action input
- $\Box$  o is an temperature observation
- $\Box$  T is a state transition function
- $\Box$  Z is an observation function

# Estimation of power state is performed by obtaining the maximum a posterior (MAP) value Based on the Bayesian approach

### Hot Spot Alerting Algorithm (1/4)

#### Estimation of junction temperature of the chip

Assume that a thermal sensor receives streams of sensor data

Initialize

• Initialize noise & error variation:  $Q^t = Q^0 R^t = R^0 E^t = R^0$ Initialize the first state:  $s^t = s^0$ ٠  $t \leftarrow t + 1$ Predict  $s^{t+1} = \mathbf{X}s^t + \mathbf{Y}a^t$ • Predict the next state: • Predict the error variance:  $E^{t+1} = \mathbf{X}E^{t}\mathbf{X}^{\mathrm{T}} + Q^{t+1}$ Update • Kalman gain:  $\mathbf{K}^{t+1} = E_{-}^{t+1} \mathbf{Z}^{\mathrm{T}} (\mathbf{Z} E_{-}^{t+1} \mathbf{Z}^{\mathrm{T}} + R^{t+1})^{-1}$ • Update the state prediction with observation:  $s^{t+1} = s^{t+1} + \mathbf{K}^{t+1}(o^{t+1} - \mathbf{Z}s^{t+1})$ • Update the error variance:  $E^{t+1} = (\mathbf{I} - \mathbf{K}^{t+1}\mathbf{Z})E_{-}^{t+1}$ 

Junction temperature estimation

### Hot Spot Alerting Algorithm (2/4)

### Estimation of power state of the system

Based on the Bayesian approach

$$Prob(b^{t} \mid h^{t}) = \frac{Prob(h^{t} \mid b^{t}) \cdot Prob(b^{t})}{Prob(h^{t})}$$

- $\Box$  *h* is a stream of action-observation pairs
- $\square$  *Prob(b<sup>t</sup> | h)* is the posterior probability density function
- $\square$  *Prob*(*h*<sup>t</sup> | *b*<sup>t</sup>) is the likelihood function
- $\square$  *Prob*(*h*<sup>t</sup>) is the prior distribution
- □ *Prob*(*b*<sup>*t*</sup>) is the probability of belief state

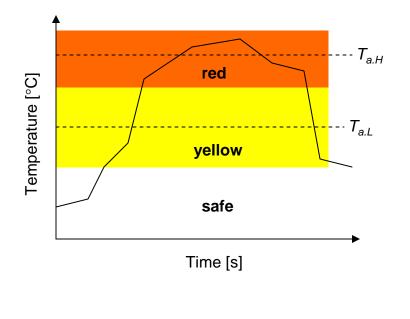
The most probable power state can be computed as MAP

$$b_{MAP} = \underset{b \in B}{\operatorname{arg max}} \operatorname{Prob}(b^{t} \mid h^{t}) = \underset{b \in B}{\operatorname{arg max}} \operatorname{Prob}(h^{t} \mid b^{t}) \cdot \operatorname{Prob}(b^{t})$$
$$= \underset{b \in B}{\operatorname{arg max}} \operatorname{Prob}(a^{t-1}, o^{t} \mid b^{t}) \cdot \operatorname{Prob}(b^{t})$$

### Hot Spot Alerting Algorithm (3/4)

#### The proposed hot spot alerting algorithm

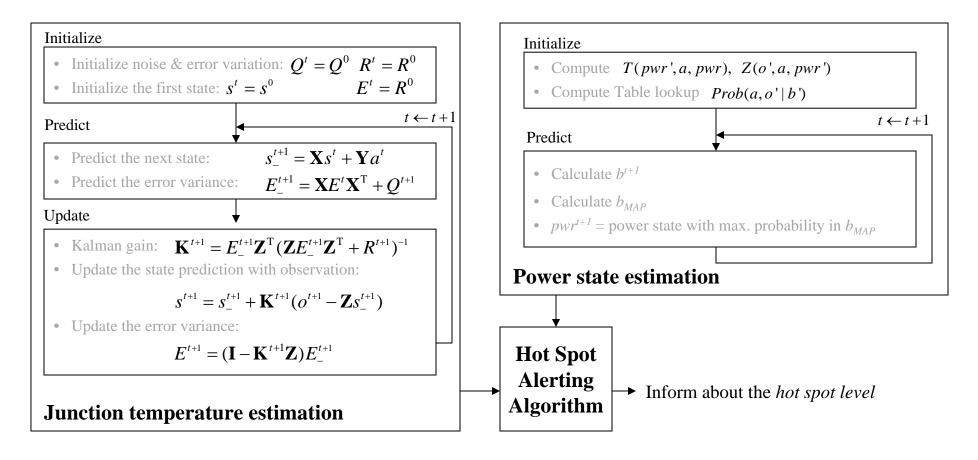
- □ Define *red* and *yellow* hot spot levels in terms of degree of thermal threat
- □  $T_{a.H}$  and  $T_{a.L}$  are pre-defined temperature thresholds ( $T_{a.L} < T_{a.H}$ )
- $\Box$   $P_a$  is a power dissipation threshold
- $\Box$   $G_{i.a}$  is a temp. gradient threshold



<i>1</i> : do 1	forever					
2:	predict the junction temperature, $T_i^{t+1}$					
3:	predict the power state of the processor, $pwr^{t+1}$					
4:	$\text{if } T_j^{t+l} \ge T_{a.H}$					
5:	alert red hot spot					
<i>6</i> :	else if $T_{a,L} \leq T_i^{t+l} < T_{a,H}$					
7:	if $pwr^{t+1} \ge P_a$					
8:	alert <i>red</i> hot spot					
<i>9</i> :	else					
10:	alert <i>yellow</i> hot spot					
<i>11</i> :	else					
12:	if $\partial T_{j} / \partial t \geq G_{j,a}$					
<i>13</i> :	alert yellow hot spot					
14: return hot spot level						

### Hot Spot Alerting Algorithm (4/4)

#### The flow of the proposed estimation technique



### **Experimental Setup**

- The technique is applied to a 32bit RISC processor
- Set the parameter values for estimation framework

		power [W] s	tate	observation [°C] state		
	pow <sub>1</sub>	pow <sub>2</sub>	pow <sub>3</sub>	0 <sub>1</sub>	<i>0</i> <sub>2</sub>	03
range	[0.6 1.4]	(1.4 2.2]	(2.2 3.0]	[86 93]	(93 100]	(100 107]

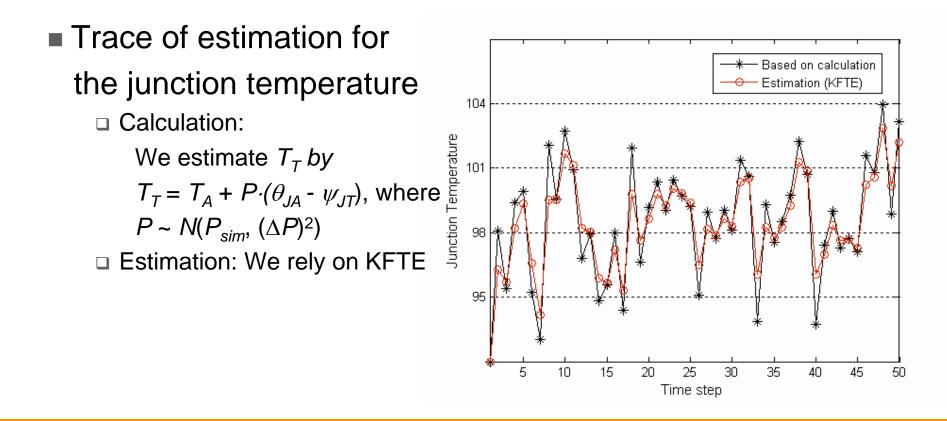
■ PBGA package thermal performance data ( $T_A$ =70°C)

Air velocity					
m/s	ft/min	$T_{J_{max}}[^{\circ}\mathrm{C}]$	$T_{T_{max}}[^{\circ}\mathrm{C}]$	$\Psi_{JT}$ [°C/W]	$\theta_{JA}$ [°C/W]
0.51	100	107.9	106.7	0.51	16.12
1.02	200	105.3	104.1	0.53	15.62
2.03	300	102.7	101.2	0.65	14.21

[ $\psi_{JT}$ : Junction-to-top of package thermal characterization parameter]

### **Experimental Results (1/3)**

Arbitrarily choose a sequence of 50 application programs
 E.g., gap<sub>1</sub> - gzip<sub>2</sub> - gap<sub>3</sub> - gcc<sub>4</sub> -...- gap<sub>50</sub>.



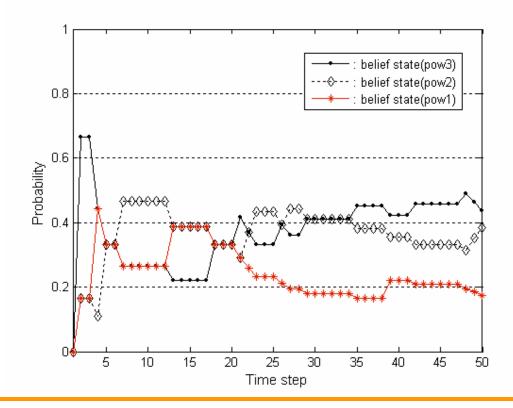
### **Experimental Results (2/3)**

#### Trace of belief state for the power state

- e.g., belief state(pow<sub>1</sub>): probability over power state pow<sub>1</sub>
- Evaluated by POMDP-based

**Power Profile Estimation** 

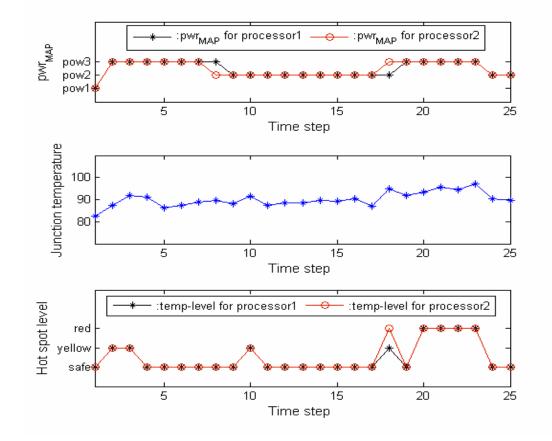
(P3E) method



### **Experimental Results (3/3)**

#### Evaluation of the proposed hot spot alerting algorithm

□ Hot spot levels defined: *red*, *yellow*, and *safe* 



### Conclusion

- The stochastic hot spot alerting technique based on
  - □ Estimation of the junction temperature of the device
  - Estimation of the power state of the system
- The proposed uncertainty-aware estimation framework efficiently captures
  - stochastic behavior of the system
  - □ PVT variations in system performance parameters, and
  - □ inaccuracies in temperature measurements
- The ability to handle uncertainty improves the accuracy and robustness of the estimation technique
- Experimental results show that the proposed technique alerts thermal threats under large variations